NZ9F2V4T5G. **SZNZ9F2V4T5G SERIES**

Zener Voltage Regulators

250 mW SOD-923 Surface Mount

This series of Zener diodes is packaged in a SOD-923 surface mount package. They are designed to provide voltage regulation protection and are especially attractive in situations where space is at a premium. They are well suited for applications such as cellular phones, hand held portables, and high density PC boards.

Specification Features:

- Standard Zener Breakdown Voltage Range 2.4 V to 24 V
- Steady State Power Rating of 250 mW
- Small Body Outline Dimensions: 0.039" x 0.024" (1.00 mm x 0.60 mm)
- Low Body Height: 0.016" (0.40 mm)
- ESD Rating of Class 3 (>16 kV) per Human Body Model
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Mechanical Characteristics:

CASE: Void-free, transfer-molded, thermosetting plastic

Epoxy Meets UL 94 V-0

LEAD FINISH: 100% Matte Sn (Tin)

MOUNTING POSITION: Any

QUALIFIED MAX REFLOW TEMPERATURE: 260°C

Device Meets MSL 1 Requirements

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Total Device Dissipation FR–5 Board, (Note 1) @ T _A = 25°C Derate above 25°C	P _D	250 2.0	mW mW/°C
Thermal Resistance from Junction–to–Ambient	$R_{\theta JA}$	500	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

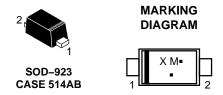
1. FR-4 Minimum Pad.



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X = Specific Device Code

M = Month Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
NZ9FxxxxT5G, SZNZ9FxxxxT5G	SOD-923 (Pb-Free)	8000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the Electrical Characteristics tables starting on page 3 of this data sheet.

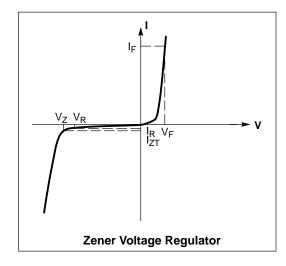
NZ9F2V4T5G, SZNZ9F2V4T5G SERIES

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted,}$

 $V_F = 0.9 \text{ V Max.} @ I_F = 10 \text{ mA for all types})$

Symbol	Parameter
VZ	Reverse Zener Voltage @ I _{ZT}
I _{ZT}	Reverse Current
Z _{ZT}	Maximum Zener Impedance @ I _{ZT}
I _{ZK}	Reverse Current
Z _{ZK}	Maximum Zener Impedance @ I _{ZK}
I _R	Reverse Leakage Current @ V _R
V_R	Reverse Voltage
I _F	Forward Current
V _F	Forward Voltage @ I _F
ΘV_Z	Maximum Temperature Coefficient of V _Z
С	Max. Capacitance $@V_R = 0$ and $f = 1$ MHz



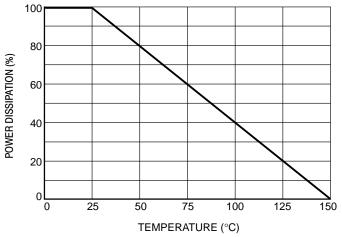


Figure 1. Steady State Power Derating

NZ9F2V4T5G, SZNZ9F2V4T5G SERIES

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted, $V_F = 0.9$ V Max. @ $I_F = 10$ mA for all types)

		Zener Voltage (Note 1) Zener Impedance		Leakage Current				С				
	Device	V _Z (V	olts)	@ I _{ZT}	Z _{ZT} @ I _{ZT}	Z _{ZK} (@ I _{ZK}	I _R @ V _R		ΘV _Z (mV/k) @ I _{ZT}		@ V _R = 0 f = 1 MHz
Device***	Marking	Min	Max	mA	Ω	Ω	mA	μΑ	Volts	Min	Max	pF
SZ, NZ9F2V4T5G	J	2.28	2.52	5	100	1000	1	50	1	-3.5	0	210
SZ, NZ9F2V7T5G	E**	2.57	2.84	5	100	1000	1	20	1	-3.5	0	210
SZ, NZ9F3V0T5G	T**	2.85	3.15	5	100	1000	1	10	1	-3.5	0	210
SZ, NZ9F3V3T5G	Q	3.14	3.47	5	100	1000	1	10	1	-3.5	0	210
SZ, NZ9F3V6T5G	3**	3.42	3.78	5	100	1000	1	10	1	-3.5	0	210
SZ, NZ9F3V9T5G	V**	3.71	4.10	5	100	1000	1	5	1	-3.5	-2.5	210
SZ, NZ9F4V3T5G	Y**	4.09	4.52	5	100	1000	1	5	1	-3.5	0	210
SZ, NZ9F4V7T5G	3	4.47	4.94	5	100	800	0.5	2	1	-3.5	0.2	150
SZ, NZ9F5V1T5G	4	4.85	5.36	5	80	500	0.5	2	1.5	-2.7	1.2	130
SZ, NZ9F5V6T5G	5	5.32	5.88	5	60	200	0.5	1	2.5	-2.0	2.5	115
SZ, NZ9F6V2T5G	6	5.89	6.51	5	60	100	0.5	1	3	0.4	3.7	110
SZ, NZ9F6V8T5G	A*	6.46	7.14	5	40	60	0.5	0.5	3.5	1.2	4.5	105
SZ, NZ9F7V5T5G	D*	7.13	7.88	5	30	60	0.5	0.5	4	2.5	5.3	100
SZ, NZ9F8V2T5G	E*	7.79	8.61	5	30	60	0.5	0.5	5	3.2	6.2	90
SZ, NZ9F9V1T5G	F*	8.65	9.56	5	30	60	0.5	0.5	6	3.8	7	80
SZ, NZ9F10VT5G	J*	9.50	10.50	5	30	60	0.5	0.1	7	4.5	8	80
SZ, NZ9F11VT5G	K*	10.45	11.55	5	30	60	0.5	0.1	8	5.4	9	80
SZ, NZ9F12VT5G	L*	11.40	12.60	5	30	80	0.5	0.1	9	6	10	80
SZ, NZ9F13VT5G	P*	12.35	13.65	5	37	80	0.5	0.1	10	7	11	75
SZ, NZ9F15VT5G	Q*	14.25	15.75	5	42	80	0.5	0.1	11	9.2	13	70
SZ, NZ9F16VT5G	R*	15.20	16.80	5	50	80	0.5	0.1	12	10.4	14	65
SZ, NZ9F18VT5G	T*	17.10	18.90	5	50	80	0.5	0.1	14	12.4	16	60
SZ, NZ9F20VT5G	V*	19.00	21.00	5	55	100	0.5	0.1	15.4	14.4	18	55
SZ, NZ9F22VT5G	Y*	20.90	23.10	5	55	100	0.5	0.1	16.8	15.4	20	55
SZ, NZ9F24VT5G	F	22.80	25.20	5	70	120	0.5	0.1	18.9	16.8	22	50

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. . *Rotated 90°.

^{**}Rotated 270°.

**Rotated 270°.

***Rotated 270°.

***SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP

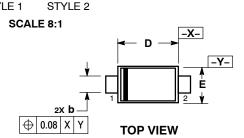
^{1.} Zener voltage is measured with a pulse test current I_Z at an ambient temperature of 25°C.

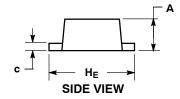


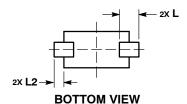


SOD-923 CASE 514AB ISSUE D

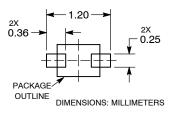
DATE 03 SEP 2020







SOLDERING FOOTPRINT*



See Application Note AND8455/D for more mounting details

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

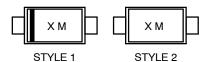
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD MAXIMUM LEAD I HICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

 DIMENSION L WILL NOT EXCEED 0.30mm.

	MIL	LIMETE	ERS	INCHES			
DIM	MIN	NOM	MAX	MIN	MOM	MAX	
Α	0.34	0.37	0.40	0.013	0.015	0.016	
b	0.15	0.20	0.25	0.006	800.0	0.010	
С	0.07	0.12	0.17	0.003	0.005	0.007	
D	0.75	0.80	0.85	0.030	0.031	0.033	
Е	0.55	0.60	0.65	0.022	0.024	0.026	
HE	0.95	1.00	1.05	0.037	0.039	0.041	
L	().19 REI	F	0.007 REF			
L2	0.05	0.10	0.15	0.002	0.004	0.006	

GENERIC MARKING DIAGRAM*



Χ = Specific Device Code

= Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

STYLE 2: NO POLARITY STYLE 1: PIN 1. CATHODE (POLARITY BAND) 2. ANODE

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DESCRIPTION:	SOD-923, 1.0X0.6X0.37, MAX HEIGHT 0.40		PAGE 1 OF 1	

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